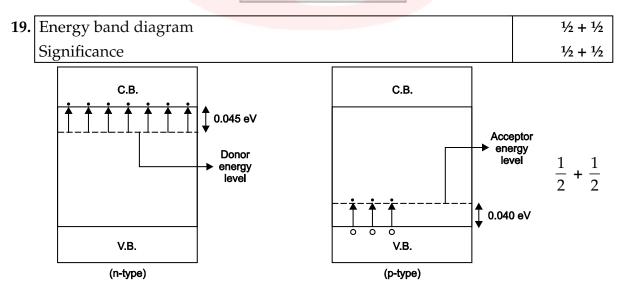
MARKING SCHEME CODE: D

SECTION A

| 1. | (C) | -q LE | 1 | | |
|-----|--------------|---|---|--|--|
| 2. | (a) | red colour | 1 | | |
| 3. | (C) | 1:3 | 1 | | |
| 4. | (d) | R = 0 | 1 | | |
| 5. | (a) | Resistivity | 1 | | |
| 6. | (b) | b) ferromagnetic material becomes paramagnetic | | | |
| 7. | (a) | electric field is changing | 1 | | |
| 8. | (a) | move in a straight line | 1 | | |
| 9. | (a) | a) binding energy per nucleon increases | | | |
| 10. | (C) | zero as diffusion and drift currents are equal and opposite | 1 | | |
| 11. | (b) | just below the conduction band | 1 | | |
| 12. | (a) | $\frac{1}{\epsilon_0}$ | 1 | | |
| 13. | (<i>d</i>) | $\frac{1}{n^2}$ | 1 | | |
| 14. | (b) | zero | 1 | | |
| 15. | (a) | both A an <mark>d R are true and</mark> R is th <mark>e</mark> correct explanation of A | 1 | | |
| 16. | (a) | Both A an <mark>d R are true and</mark> R is the correct explanation of A | 1 | | |
| 17. | (d) | A is false and R is also false | 1 | | |
| 18. | (a) | Both A and R are true and R is the correct explanation of A | 1 | | |
| | | | | | |

SECTION B



Page | 1

Significance

n-type semiconductor- small energy gap b/w donor level and conduction band which can be easily covered by thermally excited electrons.
 p-type semiconductors- small energy gap b/w acceptor level and valence band which can be easily covered by thermally excited electrons.
 y-type semiconductors- small energy gap b/w acceptor level and valence band which can be easily covered by thermally excited electrons.

OR

When *p*-type semiconductor is joined with *n*-type semiconductor, *e* from the *n*-side diffuse towards *p*-side and holes from *p*-side diffuse towards *n*-sides leaving behind a layer of immobile +ve ions on *n*-side and immobile –ve ions on *p*-side leading to formation of depletion layer. **2**

(Note: Award 1 mark, if a student draws a diagram showing depletion layer)

| | | 5 / |
|-----|--|---|
| 20. | Arrangement | 1 |
| | two uses | ¹ ⁄ ₂ + ¹ ⁄ ₂ |
| | Radiowaves < microwaves < X-rays < gamma rays | 1 |
| | Uses of microwaves | |
| | 1. Microwave oven | 1⁄2 |
| | 2. in Rader system | 1⁄2 |
| 21. | Definition | 1 |
| | Calculation of focal length | 1 |
| | One Dioptre is the power of a lens whose focal length is one metre. | 1 |
| | $\frac{1}{f} = (\mu - 1) \left(\frac{1}{R_1} - \frac{1}{R_2} \right)$ | 1/2 |
| | $R_1 = \infty$, $R_2 = -25$ cm, $\mu = 1.5$ | |
| | $\frac{1}{f} = (1.5-1)\left(\frac{1}{\infty} + \frac{1}{25}\right)$ | |
| | f = 50 cm | 1⁄2 |
| 22. | As $V = \frac{q}{C}$ | 1⁄2 |
| | dW is the W.D. in giving additional charge dq | |
| | a | |

Page | 2

This work done is stored in the form of energy of capacitor.

$$E = \frac{Q^2}{2C} = \frac{1}{2}CV^2 = \frac{1}{2}QV$$

OR

1

field inside a conductor

just outside the sphere

(*a*) Inside a conductor the electric field is zero because charges resides on the surface of sphere.

(b)
$$E = \frac{1}{4\pi\epsilon_0} \frac{q}{R^2}$$
 ¹/₂

$$E = 9 \times 10^{9} \times \frac{(110 \times 10^{-7})^{7}}{(12 \times 10^{-2})^{2}}$$
$$= 10^{5} \text{ NC}^{-1}$$

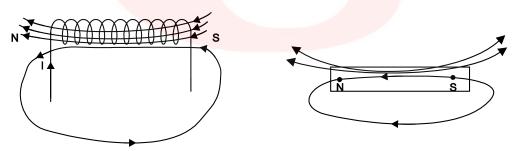
23. There are some devices which do not obey ohm's law and have non-linear I-V characteristics are called non-ohmic devices.

e.g., semiconductor devices like p-n junction diode, thermistors etc.

$$\frac{V}{I} = R \neq \text{constant}$$

(for *p*-*n* junction diode)

24. Magnetic field lines for a bar magnet and a current carrying solenoid resembles very closely.



Magnetic field on the axial line of a bar magnet is equal to the magnetic moment of an equivalent solenoid that produces the same magnetic field.

$$B = \frac{\mu_0}{4\pi} \frac{2M}{r^3}$$
 1

25. Totally reflecting prisms are used to change the path of a ray by 90° or 180°. These are the right angled glass prisms of refractive index 1.5 and critical angle

1

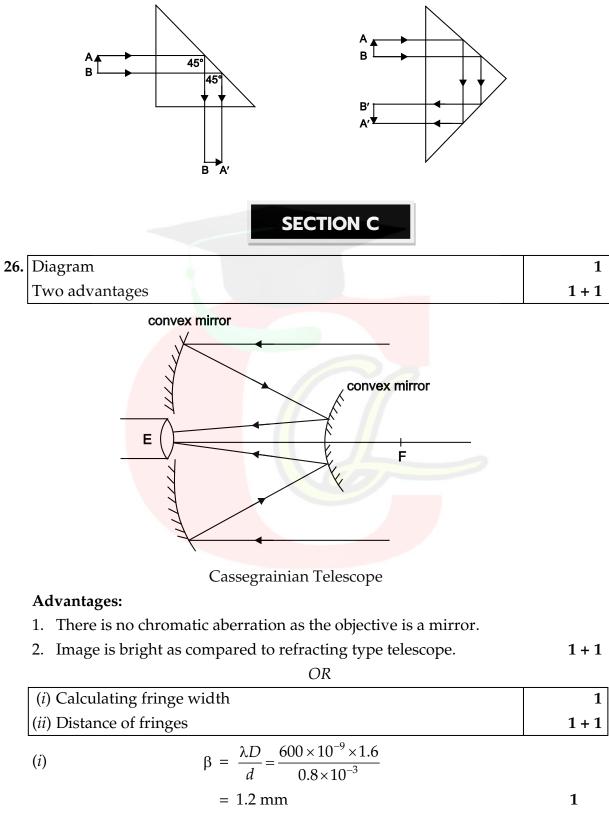
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1⁄2

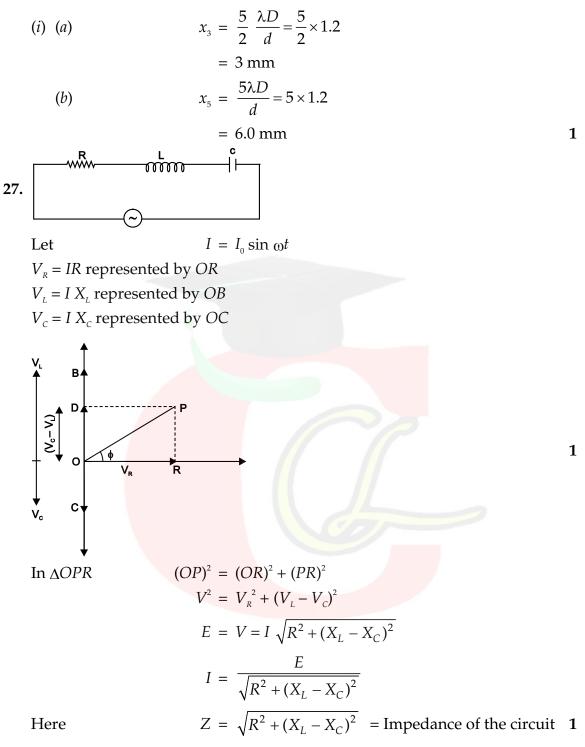
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⋪

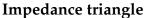
41.8°. In totally reflecting glass prisms, angle of incidence is made 45° (> *C*). Hence light suffers total internet reflection. **1**

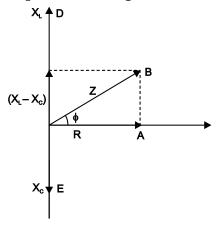


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Resistance offered by the *L*, *C* and *R* to the flow of current.

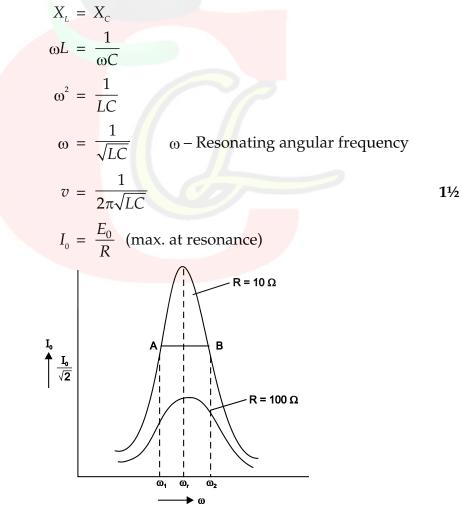




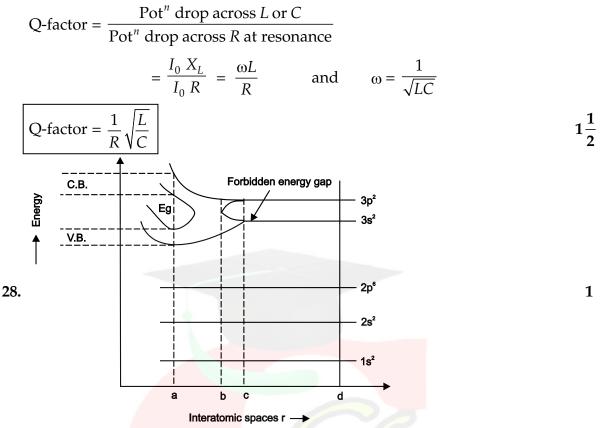
1

At low frequency X_L is small but X_C is high and at high frequency X_L is high but X_C is small. But at a frequency when $X_L = X_C$ called as resonant frequency Impedance of LCR is minimum and current through the circuit is maximum.

OR



Q-factor is the sharpness of curve at resonance.



The process of splitting of energy levels can be understood by considering the different situations.

- (*i*) When r = d No modification of energy levels.
- (*ii*) When r = c Interaction b/w outermost shell electrons of neighbouring Si atoms increases and energy gap b/w 2N 3s levels and 6N 3p levels goes on decreasing.
- (*iii*) When b < r < c Instead of single 3*s* and 3*p* level, we get large no. of closely packed level.
- (*iv*) When r = b > a The energy gap b/w 3s and 3p levels completely disappears and all the 8N levels are continuously distributed. One can say that 4N levels are filled and 4N levels are empty.
- (*v*) When r = a 4N filled levels get separated from 4N empty levels. 4N filled level form a band called valance band and 4N empty levels form a band called conduction band. 2
- **29.** Let us consider two charges -q and +q separated by certain distance 2a form a dipole of moment p = q (2*a*)

$$\vec{F}_{1} = \vec{F}_{1} + \vec{F}_{2} + \vec{F}_{2}$$

$$2 = 5I_1 + 2I_2 - I_3 \qquad \dots (1)$$

Apply KVL on loop ABDA

$$10 I_1 + 5 I_3 - 5 I_2 = 0$$

$$I_2 = 2 I_1 + I_3$$
...(2)

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Apply KVL on loop BCDB

$$5(I_1 - I_3) = 10 (I_2 + I_3) - 5 I_3 = 0$$

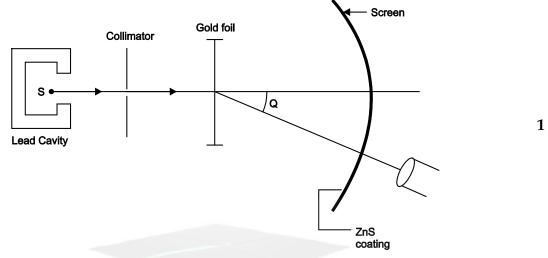
$$I_1 = 2I_2 + 4 I_3 \qquad \dots (3)$$

On solving we get

| е е | | | | |
|---|--|------------------------------------|--------------------------|--------|
| | $I_1 = \frac{4}{17} \mathbf{A}, I$ | $I_2 = \frac{6}{17} A,$ | $I_{3} = \frac{-2}{17}A$ | |
| | $I_1 + I_2 = \frac{10}{17} A$ | | | |
| | $I_1 - I_3 = \frac{6}{17} A$ | | | |
| | $I_2 + I_3 = \frac{4}{17} A$ | | | |
| | SEC | TION D | | |
| 31. (<i>i</i>) (<i>c</i>) mutual Ind | uction | | | 1 |
| | uction | | | |
| (<i>ii</i>) (<i>c</i>) frequency | | | | 1 |
| (iii) (d) soft iron | | | | 1 1 |
| (<i>iv</i>) (<i>b</i>) 2 <i>A</i> | OF | , | | T |
| (a) roduce the | | | 2 | |
| (<i>a</i>) reduce the 32. (<i>i</i>) (<i>a</i>) Photoelectr | energy loss due to ed | Juy currents | 5 | 1 |
| ., ., | | | | 1 1 |
| (<i>ii</i>) (<i>a</i>) Photons ex (<i>iii</i>) (<i>d</i>) zero | ert no pressure | | | 1 |
| (<i>iv</i>) (<i>b</i>) No. of phot | tons | | | 1 |
| | OF | 2 | | T |
| | | | | |
| | E = n h v o | or $n = \frac{L}{h\tau}$ | <u>,</u> | |
| | $n = \frac{6.0}{(6.62 \times 10^{\circ})}$ | $\frac{62}{^{-34}} \times 10^{12}$ | | |
| | $= 10^{22}$ | | | |
| | SEC | TION E | | |

| 33. | Diagram | 1 |
|-----|------------------------------|---|
| | Observations | 2 |
| | Distance of closest approach | 2 |

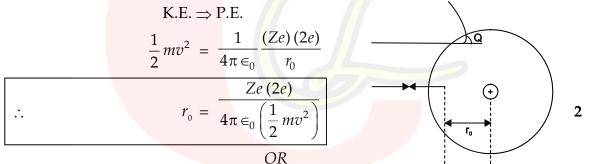
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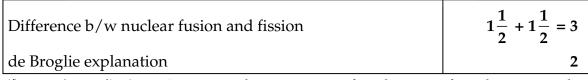


Observations:

- 1. Most of the α -particles pass without deflection.
- 2. Large no. of α -particles are scattered by very small angle.
- 3. Small no. of α -particles are scattered by large angle.
- 4. A very few no. of α -particles (1 in 8000) retraced their path.

Distance of closest approach: It is the minimum distance of α -particle from nucleus at which K.E. converts into P.E.





(*i*) **Nuclear fission:** It is a phenomenon of splitting of a heavy nuclei (A > 200) into two or more lighter nuclei.

$$^{235}U_{92} + {}^{1}n_{0} \longrightarrow {}^{141}Ba_{56} + {}^{92}Kr_{36} + 3 {}^{1}n_{0} + Q(200 \text{ Mev}) \qquad 1\frac{1}{2}$$

Nuclear fussion: It is the phenomenon of fusing two or more lighter nuclei to form a single heavy nucleus

-

2

$$^{2}H_{1} + ^{2}H_{1} \longrightarrow ^{4}He_{2} + 24 \text{ Mev}$$
 $1\frac{1}{2}$

(*ii*) Acc. to de Broglie, a stationary orbit is that which contains an integral number of de Broglie waves associated with revolving electron 1

Total distance covered 2 πr_{μ}

$$\therefore \text{ For permissible orbit } 2 \pi r_n = n\lambda \qquad \dots(1)$$
Acc. to de brogile
$$\lambda = \frac{h}{m v_n} \quad \text{Put in (1)}$$

$$\Rightarrow \qquad 2 \pi r_n = \frac{nh}{m v_n}$$
or
$$\boxed{m v_n r_n = \frac{nh}{2\pi}}$$

$$1$$
which is the quantum condition proposed by Bohr in second postulate.
Diagram
$$1$$

T,

S

or

 \Rightarrow

which is



(D)M

۵

S

Q



Principle: When a current carrying coil placed in magnetic field, it experiences a torque. 1⁄2

R

Spring

Construction: It consists of a rectangular coil PQRS of large no. of turns of insulated copper wire wound over a non-magnetic material frame. A soft iron cylindrical core is placed such that coil can rotate without touching it. Coil is suspended b/w two cylindrical magnets by a phosphor brozne wire. Upper end of the coil is connected to movable torsion head and lower end is connected to 11/2 hair spring.

Working: Function of cylindrical core and magnet is to provide radial magnetic field.

$$\tau = n I A B$$

T₁

Ν

F

If *k* is the restoring torque per unit twist and θ be the twist in the wire.

In equilibrium

 $\tau = \tau_{R} \quad \text{(Restoring torque)}$ $n I AB = k\Theta$ $I = \frac{k\Theta}{n AB}$

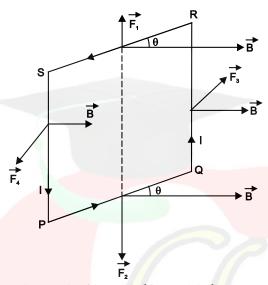
OR

$$G_{\theta} \quad \text{where } G = \frac{k}{n A B} \quad \text{galvanometer constant}$$



i.e, linear scale deflection

=



1

2

Consider a rectangular coil of length *l* breadth *b*. SP = QR = l; PQ = RS = b

 θ angle made by plane of coil with mag. field

 $\vec{F}_1 = IbB \sin \theta$ on *RS* acting \perp to both acting upward given by Right Hand Thumb Rule.

 $\vec{F}_2 = Ib B \sin\theta$ on PQ acting downward given by Right Hand Thumb Rule.

 $\vec{F}_1 \& \vec{F}_2$ are equal and opposite hence cancel each other.

1

 $\vec{F}_3 = I \, lB \sin 90^\circ = I \, lB$ acting on QR inwards by Fleming Left hand Rule.

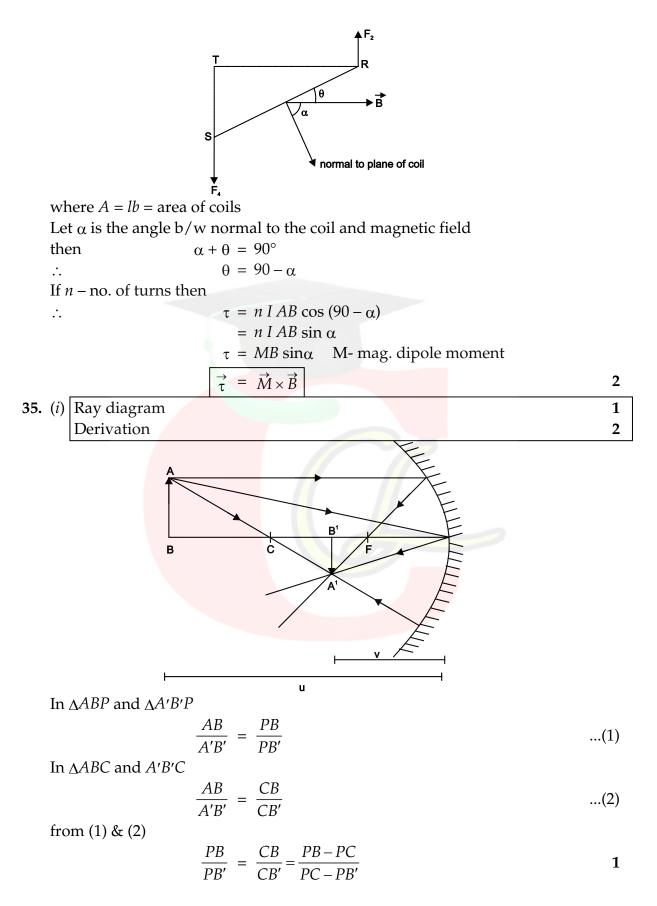
 $\vec{F}_4 = I \, lB \sin 90^\circ = I \, lB$ acting on *SP* outwards by Fleming Left hand Rule.

 $\vec{F}_3 \& \vec{F}_4$ are equal but not acting along same line and form a couple which moves the coil in magnetic field. **1**

Torque = force \times arm of couple.

$$\tau = I l B (RT)$$

= I l B b cos θ
 $\tau = I A B cos \theta$



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$$PB = -u, \qquad PB' = -v, \qquad PC = -R$$

$$\frac{-u}{-v} = \frac{-u - (-R)}{-R - (-v)}$$

$$2u v = vR + uR$$
Divide by uvR

$$\frac{2}{R} = \frac{1}{u} + \frac{1}{v}$$

$$\frac{1}{f} = \frac{1}{u} + \frac{1}{v}$$

$$\frac{1}{f} = \frac{1}{u} + \frac{1}{v}$$
(*ii*) position of image
Nature and magnification
$$\frac{1}{V_2 + V_2 = 1}$$

$$u = -10 \text{ cm} \qquad f = \frac{R}{2} = \frac{-15}{2} \text{ cm}$$

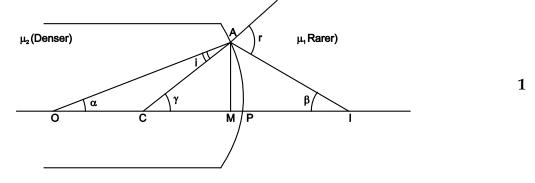
$$\frac{1}{f} = \frac{1}{u} + \frac{1}{v}$$

$$\frac{-2}{15} = \frac{1}{-10} + \frac{1}{v}$$

$$\frac{1}{v} = \frac{-2}{15} + \frac{1}{10}$$

$$v = -30 \text{ cm} \qquad 1$$
Image is real and inverted
$$m = \frac{-v}{u} = -\frac{(-30)}{(-10)} = -3$$
Image is magnified 3 times.
$$\frac{V_2}{OR}$$
Def. of Refraction
1
Diagram
1
Derivation
3
Refraction of light is the phenomenon of change in path of light when it goes from one medium to another.
1

Refraction from denser to rarer at convex spherical refracting surface.



Apply Snell's law

$$\frac{\mu_1}{\mu_2} = \frac{\sin i}{\sin r} \approx \frac{i}{r}$$

$$\mu_1 r = \mu_2 i \qquad \dots(1)$$

$$i = \gamma - \infty \qquad \text{and} \qquad r = \gamma + \beta \qquad 1$$

Put in (1)

$$\mu_{1} (\gamma + \beta) = \mu_{2} (\gamma - \infty)$$

$$\mu_{1} \left(\frac{AM}{MC} + \frac{AM}{MI} \right) = \mu_{2} \left(\frac{AM}{MC} - \frac{AM}{MO} \right)$$

If aperture is small, then

$$\mu_{1}\left(\frac{1}{PC} + \frac{1}{PI}\right) = \mu_{2}\left(\frac{1}{PC} - \frac{1}{PO}\right)$$

$$PO = -u, \quad PC = -R, \quad PI = +v$$

$$\mu_{1}\left(\frac{1}{-R} + \frac{1}{v}\right) = \mu_{2}\left(\frac{1}{-R} - \frac{1}{-\mu}\right)$$

$$\frac{\mu_{1}}{-R} + \frac{\mu_{1}}{v} = \frac{\mu_{2}}{-R} - \frac{\mu_{2}}{-u}$$

$$\frac{\mu_{2}}{-\mu} + \frac{\mu_{1}}{v} = \frac{\mu_{1} - \mu_{2}}{R}$$

2